DTMF receiver for telephones BU8871F

The BU8871F is a DTMF receiver ICs developed for use in telephone answering machines, and converts 16 different types of DTMF signals into 4-bit binary serial data. It features a wide dynamic range, eliminating the need for an external input amplifier. Expertise from a number of companies has been incorporated into these products to enable guard time control through a host microcomputer.

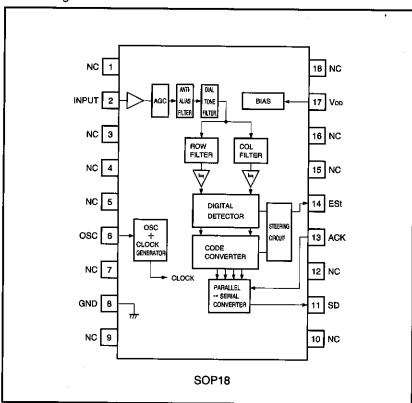
Applications

Telephone answering machines

Features

- 1) Dynamic range of 45dB. (internal AGC)
- 2) 4-bit binary serial data output.
- Guard time can be controlled through host microcomputer.
- 4) Input pins equipped with hysteresis. (ACK pin)
- 5) 4.19MHz crystal resonator can be used.

Block diagram

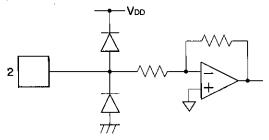


●Pin description

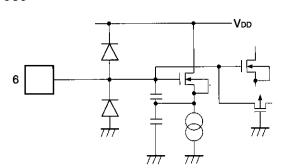
Pin No. BU8871F	Pin Name	Function
2	INPUT	This is the audio signal input pin, and should be AC coupled.
6	osc	This is the input pin for the internal oscillator. Connect a 4.194304 MHz crystal resonator between this pin and GND, or use input from an external oscillator.
8	GND	This is the ground pin.
11	SD	This is the serial data output pin. If a series of pulses is input to the ACK pin while the ESt pin is HIGH, the SD output pin outputs a 4-bit binary code corresponding to the DTMF signal shown in Table 1.
13	ACK	This is the acknowledgement pulse input pin. It is equipped with hysteresis. After the ESt pin goes HIGH, the four consecutive pulses input to the ACK pin cause the 4-bit data corresponding to the DTMF signal of the SD pin output to be output. The rising edge of the first pulse is latched before the data is shifted.
14	ESt	This is the steering signal output pin. When there is a valid DTMF signal, this pin goes HIGH.
17	Voo	This is the power supply pin.
1, 3, 4, 5, 7 9, 10, 12 15, 16, 18	NC	This is the NC pln. It is not connected inside the IC.

●Input/output circuits

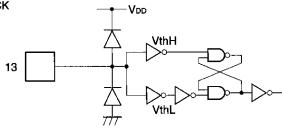
INPUT



osc

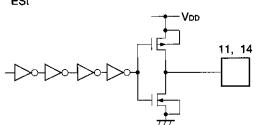


ACK



SD ESt

RBHM



183

●Absolute maximum ratings (Ta=25℃)

Parameter	Symbol	Limits	Unit V	
Power supply voltage	Voo	7		
Input voltage	Vin	GND-0.3~Vpb+0.3	٧	
Output voltage	Vouт	GND-0.3~Vpb+0.3	٧	
Power dissipation	Pd	550 * 1	mW	
Operating temperature	Topr	-10~70	r	
Storage temperature	Tstg	-55~125	°C	

^{*1} Reduced by 5.5 mW for each increase in Ta of 1 Cover 25 $^{\circ}$ C.

●Recommended operating conditions (Ta=25°C)

Parameter	Symbol	Range	Unit
Power supply voltage	Voo	4.75~5.25	V
Oscillation frequency	fosc	4.194304	MHz
Oscillation frequency deviation	Δfosc	-0.1~0.1	%

Electrical characteristics

DC characteristics (Unless otherwise noted, Ta=25°C, V_{DD}=5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	Measurement Circuit
Supply current	loo	1.0	2.2	3.4	mA		Fig.1
"H" input voltage	Vн	8.0-ddV	_	V _{DD}	٧	ACK pin	Fig.1
"L" input voltage	VIL	GND	_	GND+0.8	٧	ACK pin	Fig.1
"H" input current	lн	1 - 1	0.1	1.0	μA	ACK pin	Fig.1
"L" input current	lı∟	-	0.1	1.0	μA	ACK pin	Fig.1
Pin 1 input impedance	Zın	10	30	50	kΩ	v in=0dBm, fin=1kHz	Fig.1
"H" output saturation voltage	Voн	4.6	_	-	٧	Iон=0.4mA*2	Fig.1
"L" output saturation voltage	Vol	_	_	0.4	٧	IoL=1mA *2	Fig.1

AC characteristics (Unless otherwise noted, Ta=25°C, VDD=5.0V)

Parameter		Symbol	Mln.	Тур.	Max.	Unit	Conditions	υin (dBm)	Measurement Circuit
Valid input level range		VIV	-42	_	3	dBm	*3, 4, 5	_	Fig. 2
Dual tone level difference	Positive	VTWP	- 1	_	6	dB	*4	-15	Fig. 2
Dual tolle level dillerence	Negative	VTWN	_	-	6	dΒ	*4	-15	Fig. 2
Frequency detection range		BWA	±1.5%±2Hz		_	_	*5	-27	Fig. 2
Frequency rejection range		BWR	_	_	±4	%	*5	-27	Fig. 2
Third tone tolerance range		Ш	_	_	-16	dB	*5, 6	-27	Fig. 2
Noise tolerance range		TN	_	-12	_	dB		-27	Fig. 2
Dial tone tolerance range		TDT	_	14	7	dB	*7	-27	Fig. 2
Signal presence detection to	me	tDP	5	12	20	mS		-27	Fig. 2
Signal absence detection time		tDA	0.5	5	15	mS		-27	Fig.2
Data shift rate		fDS	-	_	1	MHz	ACK Duty 40%~60%	-	Fig. 2
Output delay		tPAD	_	70	150	nS	ACK→SD	_	Fig. 2
Setup time		tDL	0	-	_	nS		_	Fig. 2
Hold time		tDH	30	60	_	nS			Fig. 2

- **★3** Applies to ESt pin and SD pin.
- $\pmb{*}$ 4 A DTMF signal is input, and the voltage level of the single tone component is set as VIV.
- ± 5 Specified for a DTMF signal with a frequency deviation at the maximum standard frequency $\pm 0.73\%$
- *6 No difference in level between the two tones
- *7 Composite signal consisting of DTMF signals and the third harmonics of each input
- *8 Specified for signals of 350 Hz and 440 Hz ($\pm 2\%$)
- O This product is not designed to withstand radiation.

Measurement circuits

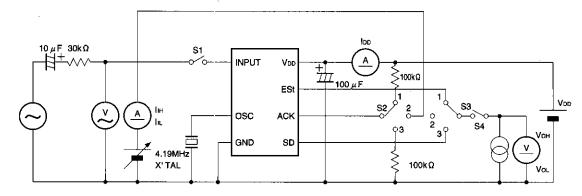


Fig. 1 DC characteristics measurement circuit

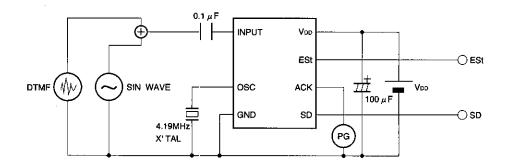


Fig. 2 AC characteristics measurement circuit

●Circuit operation

1) An overview of operation

A DTMF signal is supplied to the INPUT pin and applied to a pair of 6th-order bandpass filters, which separate the DTMF signal into its high (COL) and low (ROW) frequencies. The separated tones are converted into square waves and fed to a digital detector. (See the block diagram.)

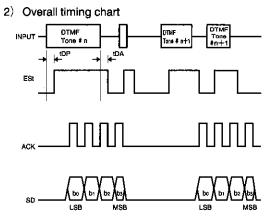
The digital detector checks the two tones to see if they are within the valid DTMF frequency bands. If they are, it sends a DETECT signal to the steering circuit, and sends the appropriate column and row address signals to a code converter.

The code converter encodes the received and detected DTMF signal, and outputs an ENABLE signal to the steering circuit.

Based on the DETECT and ENABLE signals, the steering circuit outputs an Early Steering (ESt) signal, which sets the ESt pin to HIGH, indicating that a valid DTMF signal has been detected.

If a series of pulses is input at the ACK pin while ESt is HIGH, a decoded DTMF signal is output to the SD pin as a binary code. (See Figure 3 for the overall timing.) If a pulse sequence is input at the ACK pin, the data is latched at the rising edge of the first pulse by a parallel-serial converter, and at the same time, the LSB is output from the SD pin. Following this, three bits of data are output from the SD pin for each bit of each pulse in the pulse sequence input from the ACK pin. As a result, a total of four bits of data are output for the four pulses. (See Figure 4 for the ACK and SD timing.) If the pulse sequence input to the ACK pin consists of three or fewer pulses, the next DTMF input cannot be decoded properly. Any ACK pulses in excess of four are ignored until ESt goes HIGH again.

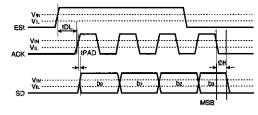
Table 1 shows the format of serial data output from the SD pin.



tDP: Signal presence detection time tDA: Signal absence detection time

Fig. 3 Overall timing chart

3) ACK and SD timing



tDL: Setup time tPAD: Output delay time tDH: Hold time

Fig. 4 ACK and SD timing

Circuit operation

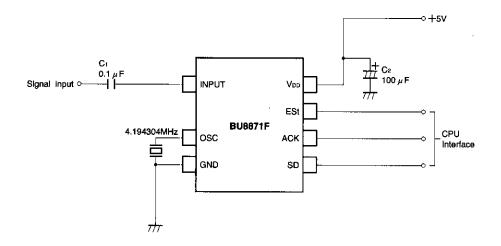
4) Serial data correspondence table

Table 1. Serial data correspondence table

ROW [Hz]	COL [Hz]	No.	b₃ (MSB)	b2	b ₁	b ₀ (LSB)
697	1209	1	0	0	0	1
697	1336	2	0	0	1	0
697	1477	3	0	0	1	1
770	1209	4	0	1	0	0
770	1336	5	0	1	0	1
770	1477	6	0	1	1	0
852	1209	7	0	1	1	1
852	1336	8	1	0	0	0
852	1477	9	1	0	0	1
941	1336	0	1	0	1	0
941	1209	*	1	0	1	1
941	1477	#	1	1	0	0
697	1633	Α	1	1	0	1
770	1633	В	1	1	1	0
852	1633	С	1	1	1	1
941	1633	D	0	0	0	0

0= "L" level ,1="H" level

Application example



Selecting attachment components

1) Power supply components

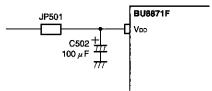


Fig. 5 Power supply circuit

JP501: This is normally shorted. To test the current consumption of the IC, insert a DC ammeter in place of JP501.

2) Oscillation components

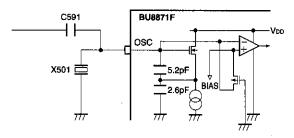


Fig. 6 Oscillation circuit

X501: Use a crystal or ceramic resonator with an oscillation frequency of 4.194304MHz. If using a ceramic resonator, there may be problems with the precision of the oscillation frequency, so please consult the manufacturer of the res-

C502: This is the Voo bypass capacitor, and is nor-

mally 100 μ F. The maximum recommended

operating power supply voltage is 5.25V, so a

voltage withstand value of 6.3V is sufficient.

onator to make sure problems will not occur.

C591: If you are using the X501 dedicated resonator designed for DTMF receivers, capacitor C591 should be left open.

If you are injecting an external clock, X501 should be omitted and DC blocking capacitor C591 used in its place. Typically, this capacitor should be 47nF.

3) DTMF input

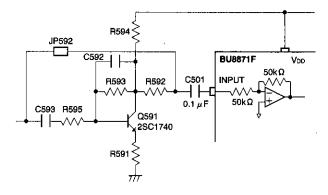


Fig. 7 DTMF input circuit

C501: This is the DC blocking capacitor. Select a capacitor that will pass DTMF signals (greater than 697Hz) without significantly attenuating the signals.

JP592: If DTMF signals are being input directly, both ends should be shorted.

Q591 — Use these to increase the sensitivity of the DTMF receiver.

Selecting attachment components

4) ESt output

The ESt guard time is determined by the CPU of the host computer, but to reduce the load on the host computer, the guard time can be set using an external circuit, as shown below.

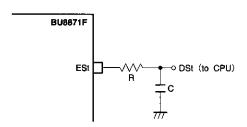


Fig. 8 Guard time setting circuit

The relation between a momentary falter in the ESt guard time (t.gl.), a momentary HIGH level in the ESt guard time (tgl.), and the time constant is shown below. Figure 10 shows a timing diagram for guard times.

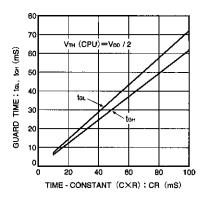


Fig. 9 Guard time vs. time constant (C × R)

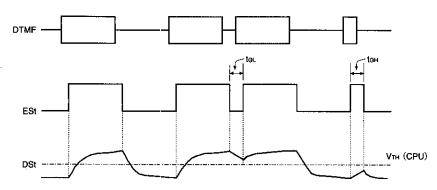


Fig. 10 Timing indicating guard times

Operation notes

Oscillation

Oscillation frequency precision can be a problem with ceramic resonators. Before including a ceramic resonator in your design, please consult the resonator manufacturer to make sure this will not be a problem.

Also, if an external clock is being injected, a DC blocking capacitor must be inserted. Select a capacitor that will neither attenuate the frequency components or put an excessive load on the drive side.

Electrical characteristic curves

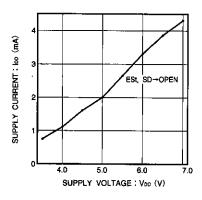


Fig. 11 Supply current vs. supply voltage characteristic

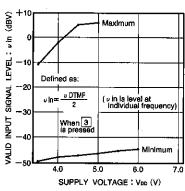


Fig. 12 Valid input level range vs. supply voltage characteristic

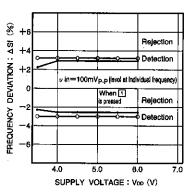


Fig. 13 Frequency detection/rejection ranges vs. supply voltage characteristic

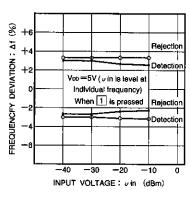


Fig. 14 Frequency detection/rejection ranges vs. input voltage characteristic

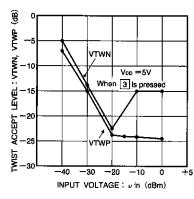


Fig. 15 2-frequency level vs. input voltage characteristic

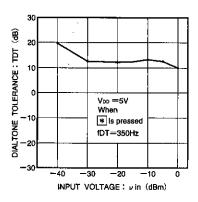


Fig. 16 Dial tone tolerance range vs. input voltage characteristic

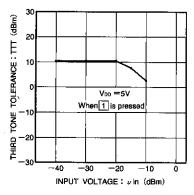


Fig. 17 Third tone tolerance range vs. input voltage characteristic

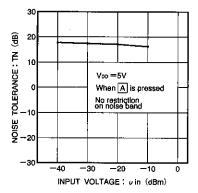
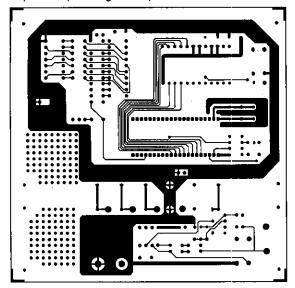


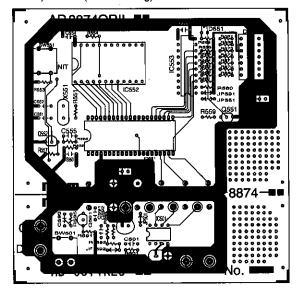
Fig. 18 Noise tolerance range vs. input voltage characteristic

- Application board patterns
- 1) Pattern (soldering surface)



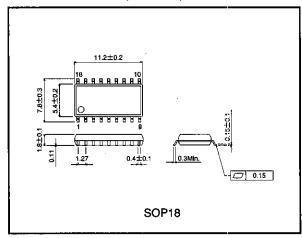
The BU8874 application board (AB-8874) can be used.

2) Pattern (silk screening)



The BU8874 application board (AB-8874) can be used.

●External dimensions (Units: mm)



Notes

- The contents described in this catalogue are correct as of March 1997.
- No unauthorized transmission or reproduction of this book, either in whole or in part, is permitted.
- The contents of this book are subject to change without notice. Always verify before use that the contents are the latest specifications. If, by any chance, a defect should arise in the equipment as a result of use without verification of the specifications, ROHM CO., LTD., can bear no responsibility whatsoever.
- Application circuit diagrams and circuit constants contained in this data book are shown as examples of standard use and operation. When designing for mass production, please pay careful attention to peripheral conditions.
- Any and all data, including, but not limited to application circuit diagrams, information, and various data, described in this catalogue are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO., LTD., disclaims any warranty that any use of such device shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes absolutely no liability in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices; other than for the buyer's right to use such devices
 itself, resell or otherwise dispose of the same; no express or implied right or license to
 practice or commercially exploit any intellectual property rights or other proprietary rights
 owned or controlled by ROHM CO., LTD., is granted to any such buyer.
- The products in this manual are manufactured with silicon as the main material.
- The products in this manual are not of radiation resistant design.

The products listed in this catalogue are designed to be used with ordinary electronic equipment or devices (such as audio-visual equipment, office-automation equipment, communications devices, electrical appliances, and electronic toys). Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers, or other safety devices) please be sure to consult with our sales representatives in advance.

Notes when exporting

- It is essential to obtain export permission when exporting any of the above products when it falls under the category of strategic material (or labor) as determined by foreign exchange or foreign trade control laws.
- Please be sure to consult with our sales representatives to ascertain whether any product is classified as a strategic material.